

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	"20030136957"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/04 10:08
L2	1	((GaN or "gallium nitride") and epitaxy and contact and "light emitting" and (AlInGaNP or "penetration layer") and etch\$3 and electrode and pad).clm.	US-PGPUB	OR	ON	2006/01/04 10:50
L3	10	lan-wen-how.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/04 10:51
L4	28	yang-kuang-neng.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/04 10:53
L5	17	chen-lung-chien.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/04 10:53